

## 30-V, N-Channel NexFET™ Power MOSFET

Check for Samples: [CSD17483F4](#)

### FEATURES

- **Low On Resistance**
- **Low  $Q_g$  and  $Q_{gd}$**
- **Low Threshold Voltage**
- **Ultra Small Footprint (0402 Case Size)**
  - 1.0 mm x 0.6 mm
- **Ultra Low Profile**
  - 0.35 mm Height
- **Integrated ESD Protection Diode**
  - Rated > 4kV HBM
  - Rated > 2kV CDM
- **Pb and Halogen Free**
- **RoHS Compliant**

### APPLICATIONS

- **Optimized for Load Switch Applications**
- **Optimized for General Purpose Switching Applications**
- **Single Cell Battery Applications**
- **Handheld and Mobile Applications**

### DESCRIPTION

The FemtoFET™ MOSFET technology has been designed and optimized to minimize the footprint in many handheld and mobile applications. This technology is capable of replacing standard small signal MOSFETs while providing at least a 60% reduction in footprint size.

### PRODUCT SUMMARY

$V_{DS}$	Drain to Source Voltage	30	V
$Q_g$	Gate Charge Total (4.5V)	1010	pC
$Q_{gd}$	Gate Charge Gate to Drain	130	pC
$R_{DS(on)}$	Drain to Source On Resistance	$V_{GS} = 1.8V$	370
		$V_{GS} = 2.5V$	240
		$V_{GS} = 4.5V$	200
$V_{GS(th)}$	Threshold Voltage	0.85	V

### ORDERING INFORMATION

Device	Qty	Media	Package	Ship
CSD17483F4	3,000	7-Inch Reel	Femto(0402) 1.0mm x 0.6mm SMD Lead Less	Tape and Reel
CSD17483F4R	18,000	13-Inch Reel		

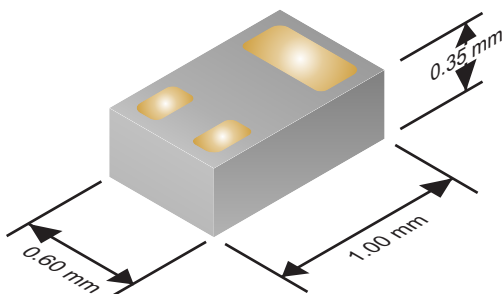
### ABSOLUTE MAXIMUM RATINGS

$T_A = 25^\circ\text{C}$ unless otherwise stated		VALUE	UNIT
$V_{DS}$	Drain to Source Voltage	30	V
$V_{GS}$	Gate to Source Voltage	12	V
$I_D$	Continuous Drain Current, $T_A = 25^\circ\text{C}^{(1)}$	1.5	A
$I_{DM}$	Pulsed Drain Current, $T_A = 25^\circ\text{C}^{(2)}$	5	A
$P_D$	Power Dissipation <sup>(1)</sup>	500	mW
ESD Rating	Human Body Model (HBM)	4	kV
	Charged Device Model (CDM)	2	kV
$T_J, T_{STG}$	Operating Junction and Storage Temperature Range	-55 to 150	$^\circ\text{C}$
$E_{AS}$	Avalanche Energy, single pulse $I_D = 7.4A$ , $L = 0.1mH$ , $R_G = 25\Omega$	2.7	mJ

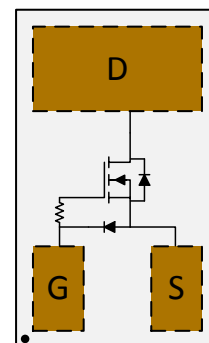
(1) Typical  $R_{\theta JA} = 90^\circ\text{C/W}$  on 1-inch<sup>2</sup> (6.45-cm<sup>2</sup>), 2-oz. (0.071-mm thick) Cu pad on a 0.06-inch (1.52-mm) thick FR4 PCB.

(2) Pulse duration  $\leq 300\mu\text{s}$ , duty cycle  $\leq 2\%$

Typical Part Dimensions



Top View



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These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

## ELECTRICAL CHARACTERISTICS

(T<sub>A</sub> = 25°C unless otherwise stated)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
Static Characteristics						
B <sub>DSS</sub>	Drain to Source Voltage	V <sub>GS</sub> = 0V, I <sub>DS</sub> = 250μA	30			V
I <sub>DSS</sub>	Drain to Source Leakage Current	V <sub>GS</sub> = 0V, V <sub>DS</sub> = 24V			1	μA
I <sub>GSS</sub>	Gate to Source Leakage Current	V <sub>DS</sub> = 0V, V <sub>GS</sub> = 10V			100	nA
V <sub>GS(th)</sub>	Gate to Source Threshold Voltage	V <sub>DS</sub> = V <sub>GS</sub> , I <sub>DS</sub> = 250μA	0.65	0.85	1.10	V
R <sub>DS(on)</sub>	Drain to Source On Resistance	V <sub>GS</sub> = 1.8V, I <sub>DS</sub> =0.5A		370	550	mΩ
		V <sub>GS</sub> = 2.5V, I <sub>DS</sub> =0.5A		240	310	mΩ
		V <sub>GS</sub> = 4.5V, I <sub>DS</sub> = 0.5A		200	260	mΩ
		V <sub>GS</sub> = 8V, I <sub>DS</sub> =0.5A		185	240	mΩ
		g <sub>fs</sub>	Transconductance	V <sub>DS</sub> = 15V, I <sub>DS</sub> = 0.5A		2.4
Dynamic Characteristics						
C <sub>iss</sub>	Input Capacitance	V <sub>GS</sub> = 0V, V <sub>DS</sub> = 15V, f = 1MHz		145	190	pF
C <sub>oss</sub>	Output Capacitance			42	55	pF
C <sub>rss</sub>	Reverse Transfer Capacitance			2	3	pF
R <sub>G</sub>	Series Gate Resistance	V <sub>DS</sub> = 15V, I <sub>DS</sub> = 0.5A		23		Ω
Q <sub>g</sub>	Gate Charge Total (4.5V)			1010	1300	pC
Q <sub>gd</sub>	Gate Charge Gate to Drain			130		pC
Q <sub>gs</sub>	Gate Charge Gate to Source			220		pC
Q <sub>g(th)</sub>	Gate Charge at V <sub>th</sub>			145		pC
Q <sub>oss</sub>	Output Charge		V <sub>DS</sub> = 15V, V <sub>GS</sub> = 0V		1095	
t <sub>d(on)</sub>	Turn On Delay Time	V <sub>DS</sub> = 0V, V <sub>GS</sub> = 4.5V, I <sub>DS</sub> = 0.5A,R <sub>G</sub> = 2Ω		3.3		ns
t <sub>r</sub>	Rise Time			1.3		ns
t <sub>d(off)</sub>	Turn Off Delay Time			10.6		ns
t <sub>f</sub>	Fall Time			3.4		ns
Diode Characteristics						
V <sub>SD</sub>	Diode Forward Voltage	I <sub>SD</sub> = 0.5A, V <sub>GS</sub> = 0V		0.73	0.9	V
Q <sub>rr</sub>	Reverse Recovery Charge	V <sub>DS</sub> = 15V, I <sub>F</sub> = 0.5A, di/dt = 300A/μs		1475		pC
t <sub>rr</sub>	Reverse Recovery Time			5.5		ns

## THERMAL CHARACTERISTICS

(T<sub>A</sub> = 25°C unless otherwise stated)

PARAMETER		Typical Values	UNIT
R <sub>θJA</sub>	Thermal Resistance Junction to Ambient <sup>(1)</sup>	90	°C/W
	Thermal Resistance Junction to Ambient <sup>(2)</sup>	250	°C/W

(1) Device mounted on FR4 material with 1-inch<sup>2</sup> (6.45-cm<sup>2</sup>), 2-oz. (0.071-mm thick) Cu.

(2) Device mounted on FR4 material with minimum Cu mounting area.

## TYPICAL MOSFET CHARACTERISTICS

( $T_A = 25^\circ\text{C}$  unless otherwise stated)

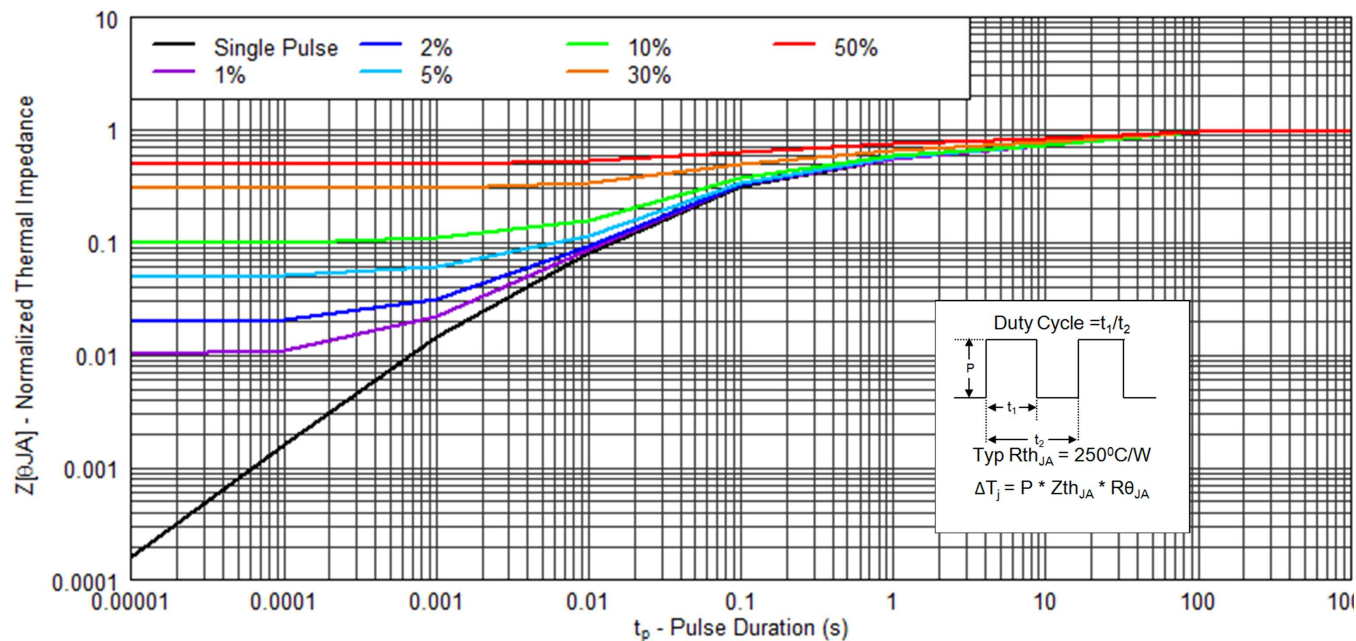


Figure 1. Transient Thermal Impedance

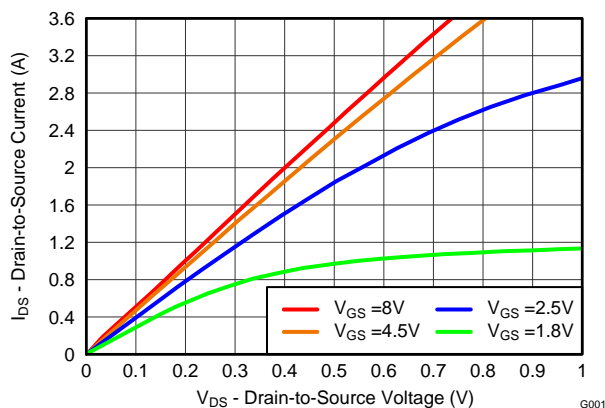


Figure 2. Saturation Characteristics

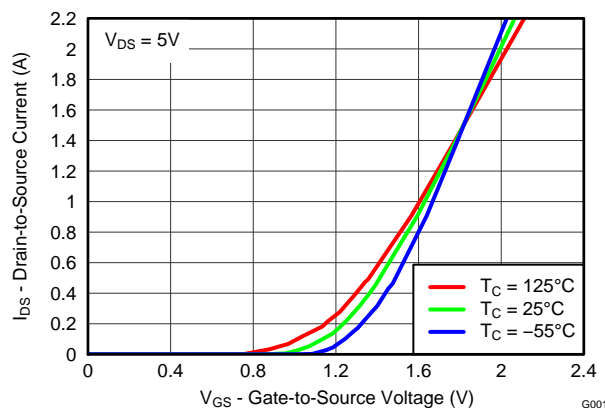


Figure 3. Transfer Characteristics

## TYPICAL MOSFET CHARACTERISTICS (continued)

( $T_A = 25^\circ\text{C}$  unless otherwise stated)

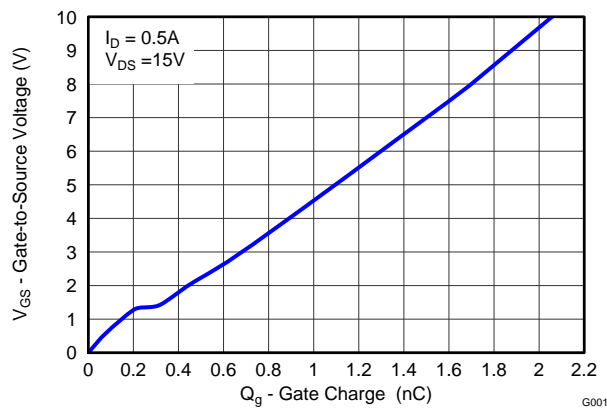


Figure 4. Gate Charge

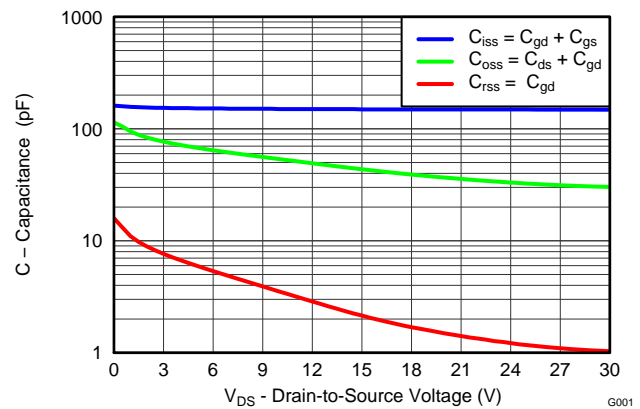


Figure 5. Capacitance

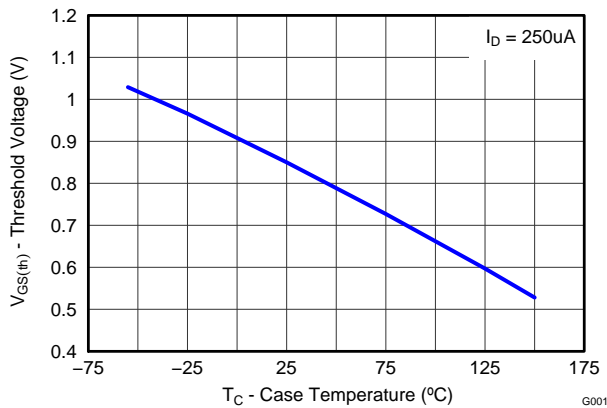


Figure 6. Threshold Voltage vs. Temperature

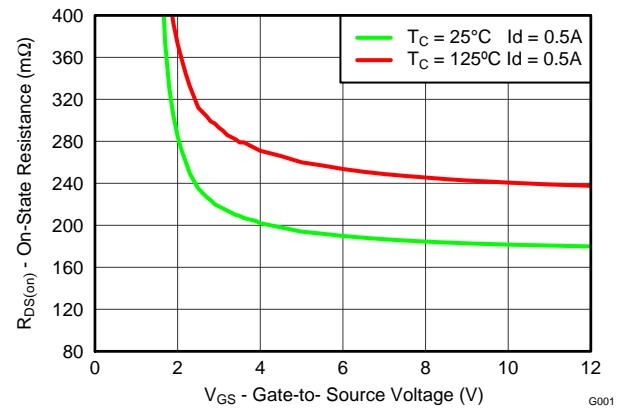


Figure 7. On-State Resistance vs. Gate-to-Source Voltage

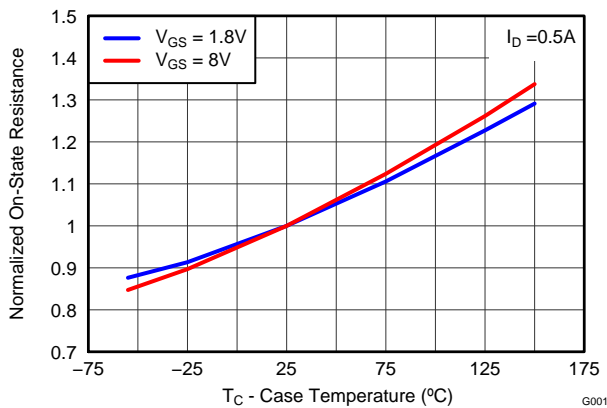


Figure 8. Normalized On-State Resistance vs. Temperature

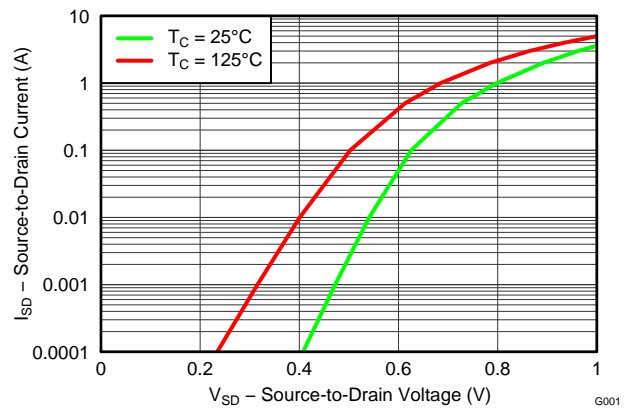
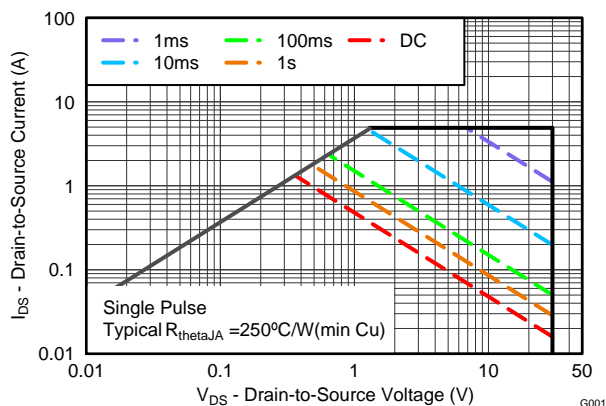


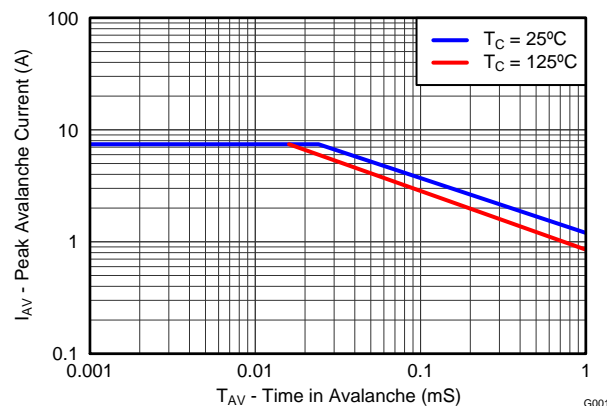
Figure 9. Typical Diode Forward Voltage

## TYPICAL MOSFET CHARACTERISTICS (continued)

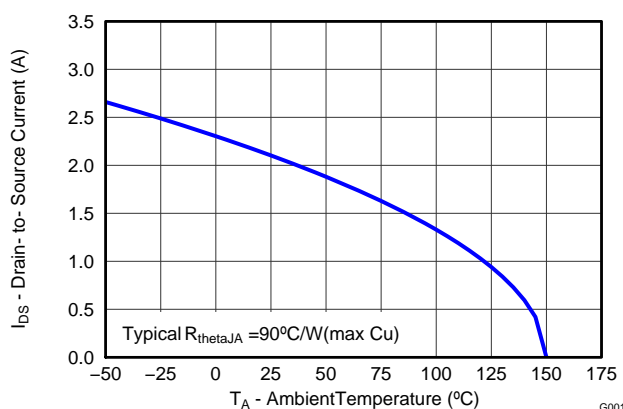
( $T_A = 25^\circ\text{C}$  unless otherwise stated)



**Figure 10. Maximum Safe Operating Area**



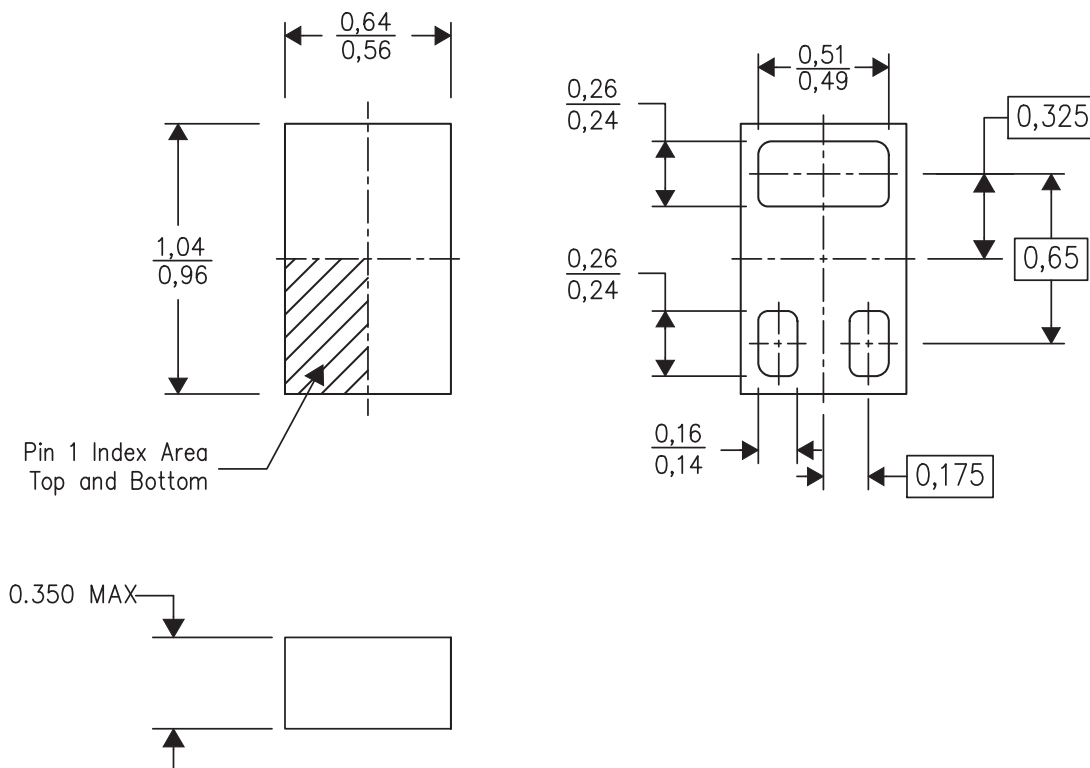
**Figure 11. Single Pulse Unclamped Inductive Switching**



**Figure 12. Maximum Drain Current vs. Temperature**

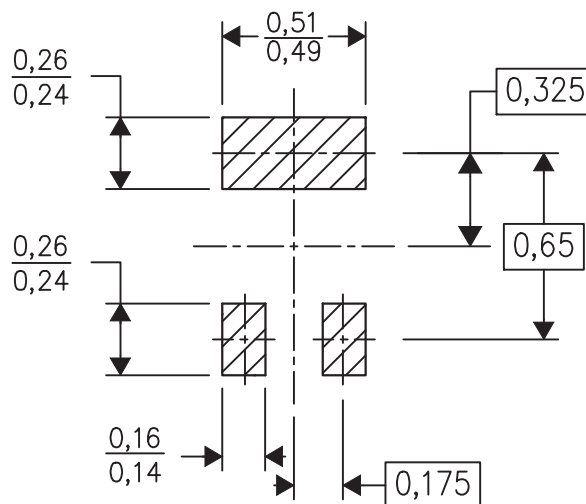
## MECHANICAL DATA

### 0402 Mechanical Dimensions



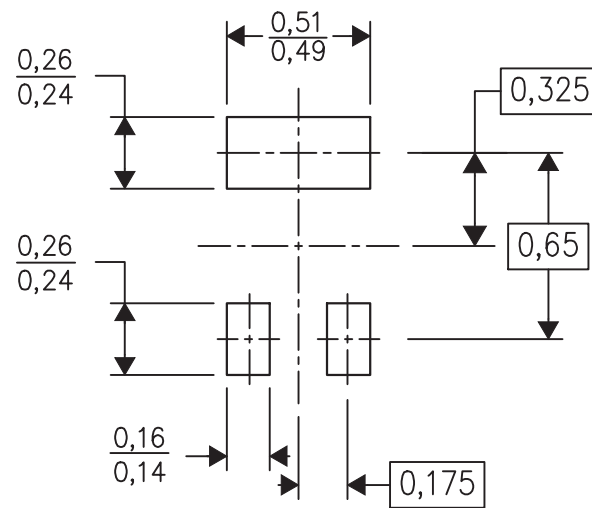
- (1) All linear dimensions are in millimeters (dimensions and tolerancing per AME T14.5M-1994)
- (2) This drawing is subject to change without notice
- (3) This package is a PB-Free solder land design

### Recommended Minimum PCB Layout



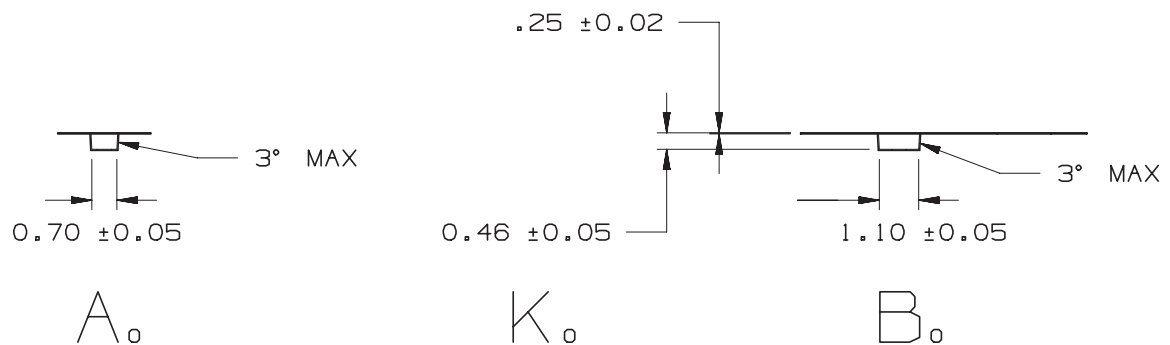
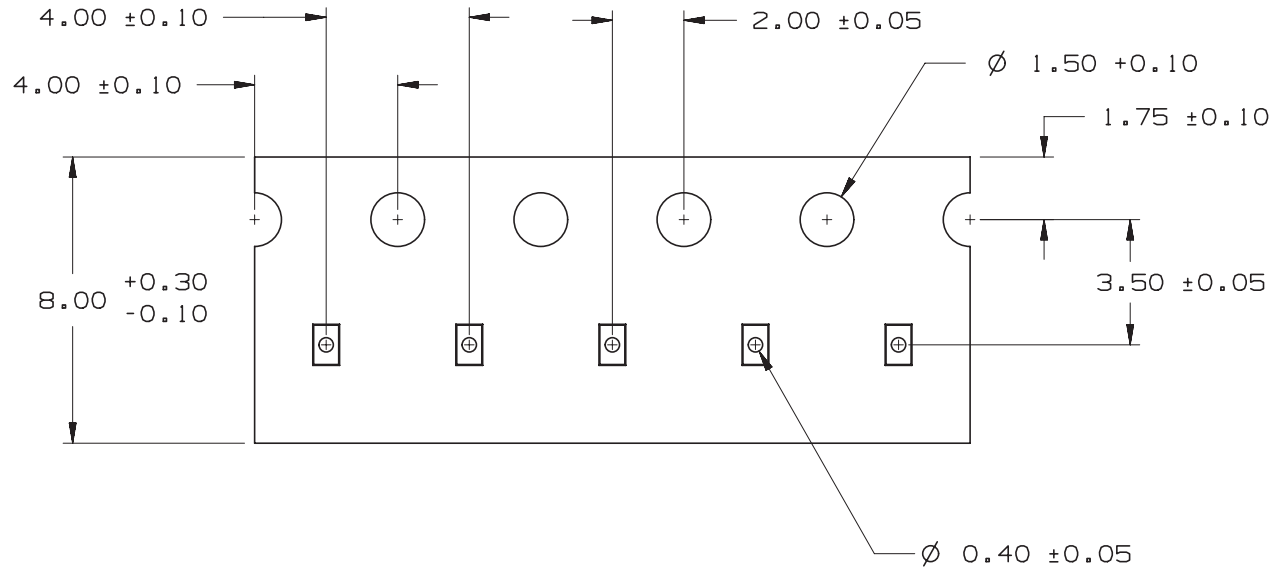
- (1) All dimensions are in millimeters.

## Recommended Stencil Pattern



(1) All dimensions are in millimeters.

## CSD17483F4 Embossed Carrier Tape Dimensions



- (1) Pin 1 will be oriented in the top right quadrant of the tape enclosure (Quadrant 2), closest to the carrier tape sprocket holes.



## PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
CSD17483F4	ACTIVE	PICOSTAR	YJC	3	3000	Green (RoHS & no Sb/Br)	Call TI	Level-1-250C-UNLIM	-55 to 150	DP	<a href="#">Samples</a>
CSD17483F4R	PREVIEW	PICOSTAR	YJC	3	18000	TBD	Call TI	Call TI	-55 to 150		

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

**Green (RoHS & no Sb/Br):** TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

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